P-Channel 30-V (D-S) MOSFET

Top View

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)			
- 30	0.004 at V _{GS} = - 10 V	- 120	130 nC			
- 30	0.006 at V _{GS} = - 4.5 V	- 100	130 110			

Bottom View

DFN5X6

- PIN1

Top View

FEATURES

- Halogen-free
- TrenchFET[®] Power MOSFET
- 100 % R_g Tested •

APPLICATIONS

Notebook

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- Load Switch



P-Channel MOSFET

D

S

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 30	V	
Gate-Source Voltage		V _{GS}	± 20	v	
Continuous Drain Current (T _J = 150 °C)	$T_{C} = 25 °C$ $T_{C} = 70 °C$ $T_{A} = 25 °C$ $T_{A} = 70 °C$	I _D	- 120 ^a - 100 ^a - 31.6 ^{b, c} - 25.3 ^{b, c}		
Pulsed Drain Current		I _{DM}	- 360	A	
Continuous Source-Drain Diode Current	T _C = 25 °C T _A = 25 °C	I _S	- 80 ^a - 56 ^{b, c}	_	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	- 60		
Single Pulse Avalanche Energy	L = 0.1 mm	E _{AS}	160	mJ	
Maximum Power Dissipation	$T_{C} = 25 °C$ $T_{C} = 70 °C$ $T_{A} = 25 °C$ $T_{A} = 70 °C$	P _D	110 83 6.95 ^{b, c} 5.0 ^{b, c}	w	
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	- 55 to 150	℃		
Soldering Recommendations (Peak Temperature	Ŭ	260			

THERMAL RESISTANCE RATINGS								
Parameter		Symbol	Typical	Maximum	Unit			
Maximum Junction-to-Ambient ^{b, f}	t ≤ 10 s	R _{thJA}	15	20	°C/W			
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	0.9	1.2	0/11			

Notes:

a. Package limited.

b. Surface Mounted on 1" x 1" FR4 board.

c. t = 10 s.

d. The DFN5x6 is a leadless package. The end of the lead terminal is exposed

copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

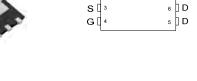
e. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

f. Maximum under Steady State conditions is 54 °C/W.

Din-Tek SEMICONDUCTOR



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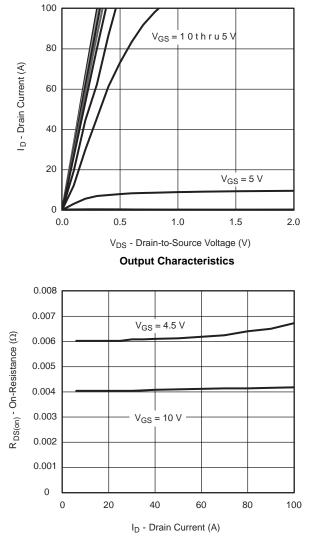
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_{D} = -250 \mu A$	- 30			V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	T _J I _D = - 250 μA		- 31		m\//º(
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	i _D = - 250 μA		6.5		mV/°(
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1.0		- 3.0	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zana Cata Maltana Drain Current	I _{DSS}	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1	μA
Zero Gate Voltage Drain Current		$V_{DS} = -30$ V, $V_{GS} = 0$ V, $T_{J} = 55$ °C			- 10	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 30			Α
	D	V _{GS} = - 10 V, I _D = - 20 A		0.004	0.005	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 15 A		0.006	0.007	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 20 A		97		S
Dynamic ^b						
Input Capacitance	C _{iss}			7050		pF
Output Capacitance	C _{oss}	V_{DS} = - 15 V, V_{GS} = 0 V, f = 1 MHz		1375		
Reverse Transfer Capacitance	C _{rss}			1215		
Total Gate Charge	Qg	V_{DS} = - 15 V, V_{GS} = - 10 V, I_D = - 20 A		130	250	nC
				78	130	
Gate-Source Charge	Q _{gs}	$V_{\rm DS}$ = - 15 V, $V_{\rm GS}$ = - 4.5 V, $I_{\rm D}$ = - 20 A		29		
Gate-Drain Charge	Q _{gd}			37		
Gate Resistance	Rg	f = 1 MHz		1.9		Ω
Turn-On Delay Time	t _{d(on)}			25	40	
Rise Time	t _r	V_{DD} = - 15 V, R _L = 15 Ω		15	30	- ns
Turn-Off Delay Time	t _{d(off)}	$I_{D}\cong$ - 1.0 A, V_{GEN} = - 10 V, R_{g} = 1 Ω		110	170	
Fall Time	t _f			30	50	
Turn-On Delay Time	t _{d(on)}			110	170	
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		100	150	
Turn-Off Delay Time	t _{d(off)}	$\rm I_D \cong$ - 1.0 A, $\rm V_{GEN}$ = - 4.5 V, $\rm R_g$ = 1 Ω		100	150	
Fall Time	t _f			50	75	
Drain-Source Body Diode Characteristic	cs					
Continuous Source-Drain Diode Current	ا _S	T _C = 25 °C			120	A
Pulse Diode Forward Current ^a	I _{SM}				360	
Body Diode Voltage	V _{SD}	I _S = - 5 A		- 0.54	- 1.1	V
Body Diode Reverse Recovery Time	t _{rr}			50	100	ns
Body Diode Reverse Recovery Charge	Q _{rr}	I _F = 3.5 A, dl/dt = 100 A/μs, T _{.1} = 25 °C		65	130	nC
Reverse Recovery Fall Time	t _a	$r_{\rm F} = 5.5$ A, unut = 100 A/µs, $r_{\rm J} = 25$ °C		26		
Reverse Recovery Rise Time	t _b			24		ns

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

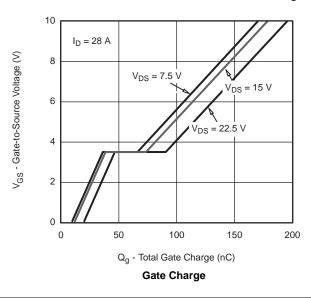
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

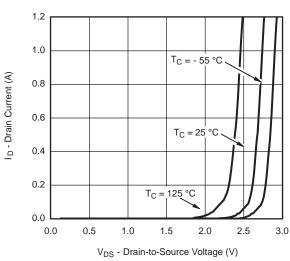




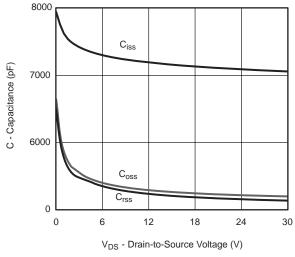
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



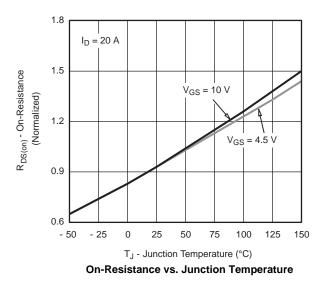




Transfer Characteristics



Capacitance



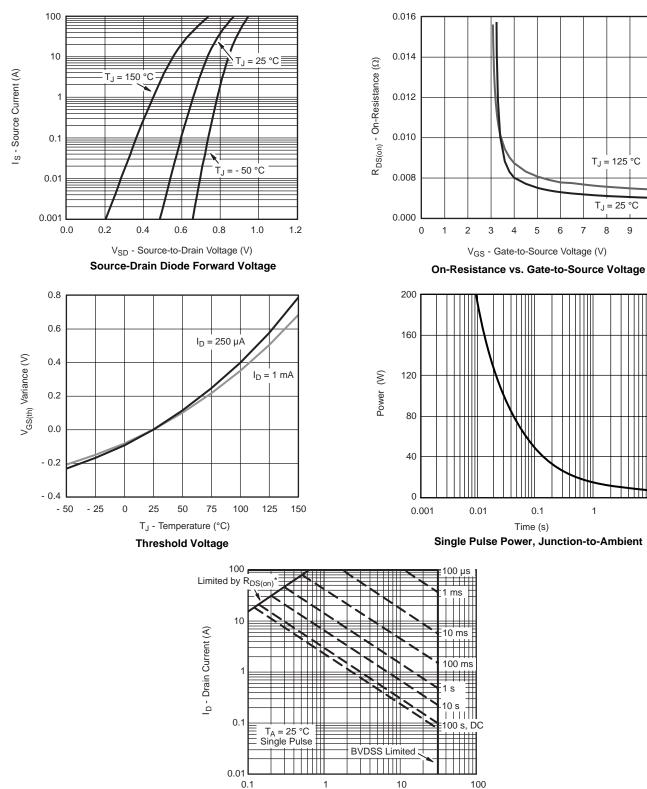


T_J = 125 °C

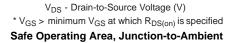
T_J = 25 °C

0.1

Time (s)

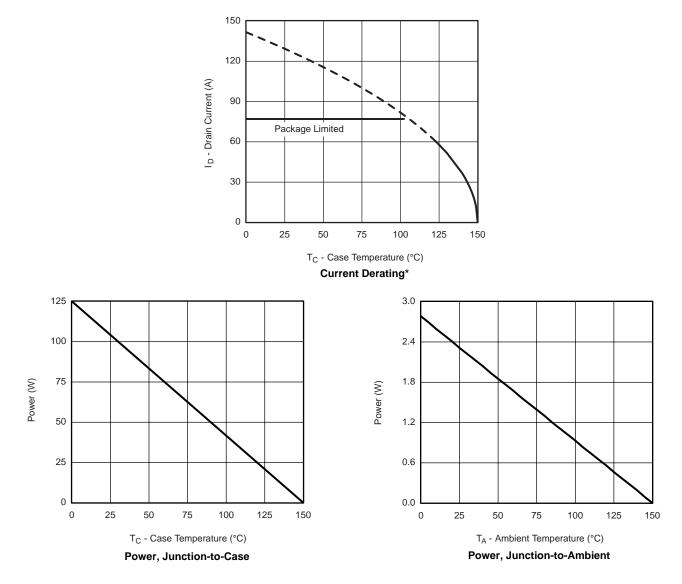


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



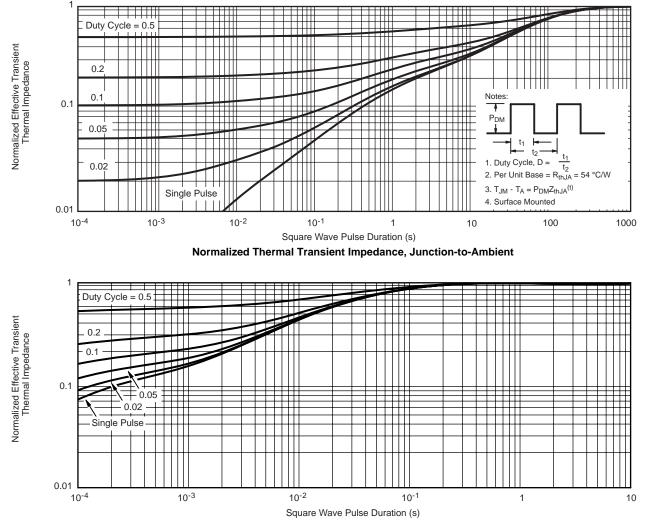


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



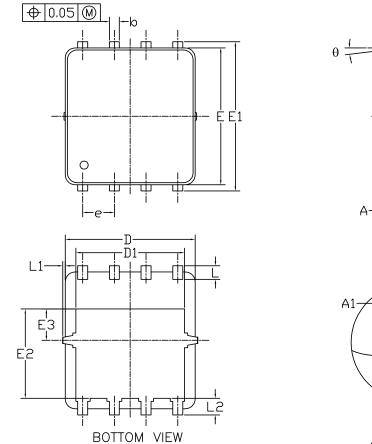


Normalized Thermal Transient Impedance, Junction-to-Case

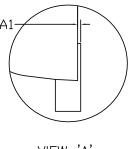
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VIEW 'A'

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DFN5x6_8L_EP1_P PACKAGE OUTLIN



<u>VIEW 'A'</u> (SCALE 5:1)

RECOMMENDED LAND PATTERN .60 -0.55 0.50 -0.77 -0.635 4.12 6.15 -1.60 + $\left|+\right|$ + 0.65 +ŧ -11.27-0.50-

SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES			
SIMBOLS	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.85	0.95	1.00	0.033	0.037	0.039	
A1	0.00		0.05	0.000		0.002	
b	0.30	0.40	0.50	0.012	0.016	0.020	
с	0.15	0.20	0.25	0.006	0.008	0.010	
D	5.10	5.20	5.30	0.201	0.205	0.209	
D1	4.25	4.35	4.45	0.167	0.171	0.175	
Е	5.45	5.55	5.65	0.215	0.219	0.222	
E1	5.95	6.05	6.15	0.234	0.238	0.242	
E2	3.525	3.625	3.725	0.139	0.143	0.147	
E3	1.175	1.275	1.375	0.046	0.050	0.054	
e	1.27 BSC			0.050 BSC			
L	0.45	0.55	0.65	0.018	0.022	0.026	
L1	0		0.15	0		0.006	
L2	0.68 REF			0.027 REF			
θ	0°		10°	0°		10°	

NOTE

UNIT: mm

 PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS. MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 6 MILS EACH.
 CONTROLLING DIMENSION IS MILLIMETER.

CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.



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